MSRTT20060(A)D(R) THRU MSRTT200160(A)D(R)

HIGH POWER DIODE MODULE TYPES 200A

Features

High Surge Capability
Types up to 1600V V_{RRM}
Isolation Type Package
Electrically Isolation base plate

Maximum Ratings

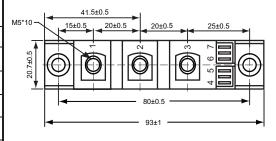
Junction Operating Temperature : -40°C to +175°C

Storage Temperature : -40°C to +175°C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
MSRTT20060(A)D(R)	600V	420V	600V
MSRTT20080(A)D(R)	800V	560V	800V
MSRTT200100(A)D(R)	1000V	700V	1000V
MSRTT200120(A)D(R)	1200V	840V	1200V
MSRTT200140(A)D(R)	1400V	980V	1400V
MSRTT200160(A)D(R)	1600V	1120V	1600V



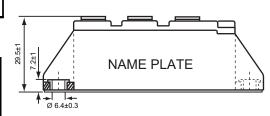
Dimensions in mm (1 mm = 0.0394")

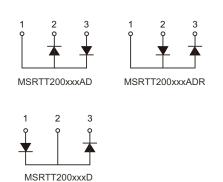


Electrical Characteristics @ 25 $^{\circ}$ C Unless Otherwise Specified

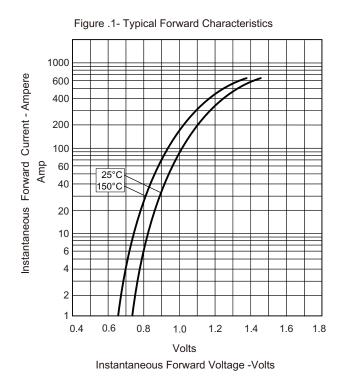
Average Forward Current (Per diode)	lf(AV)	200A	Tc = 125°C
Peak Forward Surge Current (Per diode)	lгsм	3000A	8.3ms , half sine
Maximum (Per diode) Instantaneous Forward Voltage *	VF	1.10V	IFM=200A;ТJ = 25°С
Maximum Instantaneous Reverse Current At Rated DC Blockig Voltage* (Per diode)	lr	10 <i>μ</i> A 5mA	T _J = 25°C T _J = 150°C
Isolation Voltage	Visol	2500V	A.C. 1minute
Maximum Thermal Resistance Junction To Case (Per diode)	R ₀ j c	0.35°C/W	
Mounting torque		5 ± 0.5Nm 3 ± 0.5Nm	to heatsink to terminals

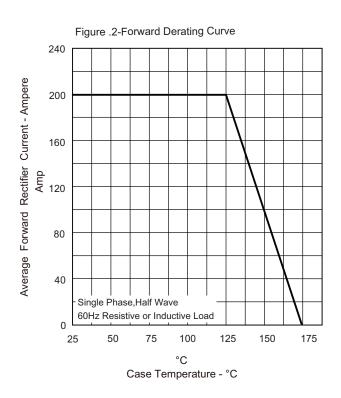
^{*}Pulse Test: Pulse Width 300 μ sec, Duty Cycle < 2%

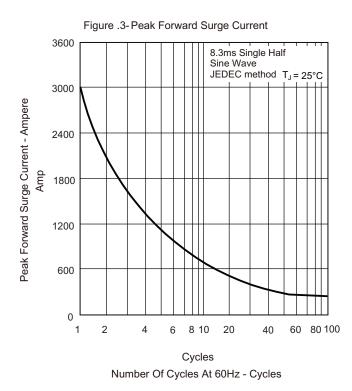


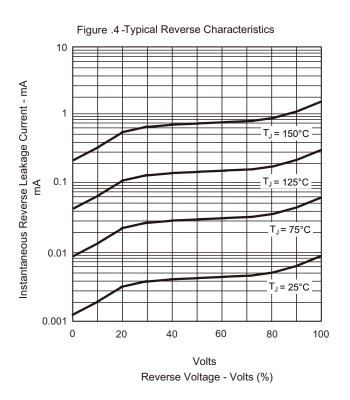


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